

NCE75TD120BT

1200V, 75A, Trench FS II Fast IGBT

General Description:

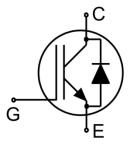
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Inverters
- Motor drives
- Converter



Schematic diagram

Package Marking and Ordering Information

Device	Device Package	Device Marking		
NCE75TD120BT	TO-247	NCE75TD120BT		



TO-247

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
Vces	Collector-Emitter Voltage	1200	V
V_{GES}	Gate- Emitter Voltage	±30	V
I-	Collector Current	150	А
lc	Collector Current @T _C = 100 °C	75	А
I _{Cpuls}	Pulsed Collector Current, t _p limited by T _{jmax}	225	A
-	turn off safe operating area, V _{CE} =1200V, Tj=150°C	225	A
l _F	Diode Continuous Forward Current @Tc = 100 °C	75	A
I _{FM}	Diode Maximum Forward Current	225	A
Б	Power Dissipation @ T _C = 25°C	833	W
P _D	Power Dissipation @T _C = 100 °C	417	W
T _J ,T _{stg}	Operating Junction and Storage Temperature Range	-55 to +175	°C
TL	Maximum Temperature for Soldering	260	°C
t_{sc}	Short circuit withstand time V_{GE} =15.0V, V_{CC} \leq 600V, Allowed number of short circuits<1000Time between short circuits: \geq 1.0s, T_j \leq 150°C	10	us

Wuxi NCE Power Co., Ltd



NCE75TD120BT

PbFreeProduct

Thermal Characteristic

Symbol	Parameter	Value	Units
Rejc	Thermal Resistance, Junction to case for IGBT	0.18	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	0.4	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	40	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Councile of	Developed	Test Conditions		Value			1114-
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics						
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	,I _{CE} =1mA	1200			V
Ices	Collector-Emitter Leakage Current	V _{GE} =0V,	/ _{CE} =1200V			5	uA
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30V,V _{CE} =0V				200	nA
I _{GES(R)}	Gate to Source Reverse Leakage	V _{GE} =-30	V,Vce =0V			200	nA
V	Collector Emitter Seturation Voltage	Ic=75A	Tj=25°C		1.55	1.8	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{\text{GE}}=15V$	Tj=150°C		1.8		V
V _{GE(th)}	Gate Threshold Voltage	Ic=1mA	,Vce=Vge	5.0		6.5	V
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: ≥1.0s	V _{GE} =15V,V _{CC} ≤600V, t _{SC} ≤10us,Tj≤150°C			500		Α
Dynamic Ch	aracteristics						
Cies	Input Capacitance	V _{CE} =30V,V _{GE} =0V, f=1MHz			9747		pF
Coes	Output Capacitance				327		
Cres	Reverse Transfer Capacitance				271		
Qg	Total Gate Charge				572		
Q _{ge}	Gate to Emitter Charge	Vcc=960V, Ic=75A, Vg==15V			69		nC
Q _{gc}	Gate to Collector Charge	VGL	-101		368		
Switching Cl	haracteristics						
t _{d(ON)}	Turn-on Delay Time			-	19		
tr	Rise Time				17		no
t _{d(OFF)}	Turn-Off Delay Time	V_{CE} =600V, I_{C} =75A, V_{GE} =0/15V, R_{g} =8 Ω Inductive Load			170		ns
t _f	Fall Time				18		
Eon	Turn-On Switching Loss				6.7		
E _{off}	Turn-Off Switching Loss				3.7		mJ
E _{ts}	Total Switching Loss				10.4		

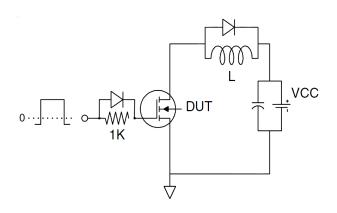
Electrical Characteristics of the Diode(Tc= 25°C unless otherwise specified):

Symbol	Parameter	Test Conditions	Rating			Units
			Min.	Тур.	Max.	Ullits
V _{FM}	Diode Forward Voltage	I _F =75A		2.2	2.8	V
Trr	Reverse Recovery Time	I- 27.5A		180		ns
I _{RRM}	Diode Peak Reverse Recovery Current	I _F =37.5A,		29		Α
Qrr	Reverse Recovery Charge	di/dt=800A/us		4.3		uC
Pulse width $t_{tp} \le 380 \mu s, \delta \le 2\%$						

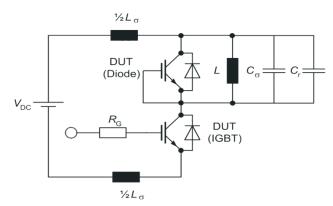


Test Circuit

1) Gate Charge Test Circuit

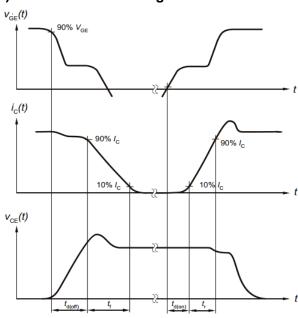


2) Switch Time Test Circuit

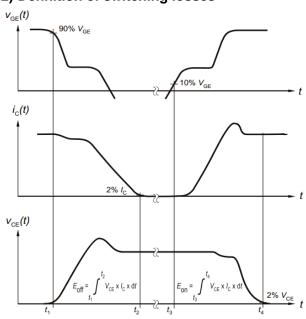


Switching characteristics

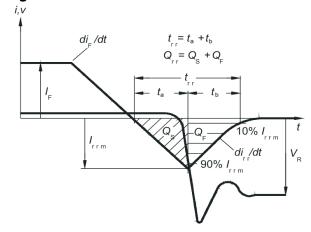
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics





Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

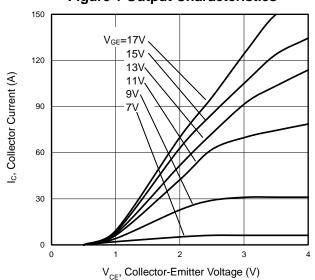


Figure 3 V_{CE(sat)} vs. Case Temperature

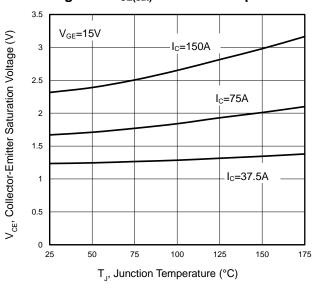


Figure 5 Capacitance Characteristics

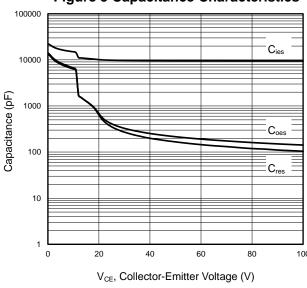


Figure 2 Transfer Characteristics

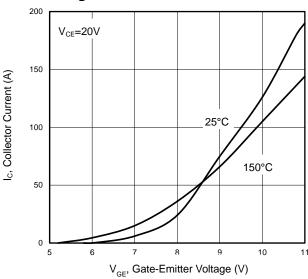


Figure 4 Saturation Voltage vs. V_{GE}

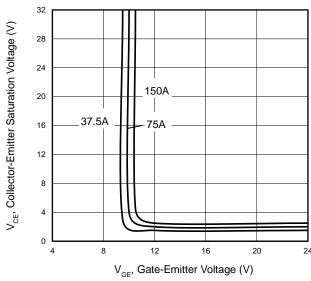
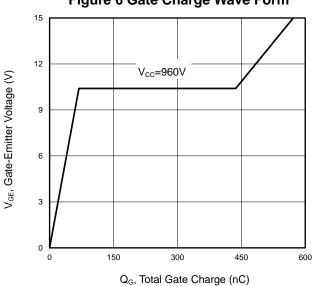
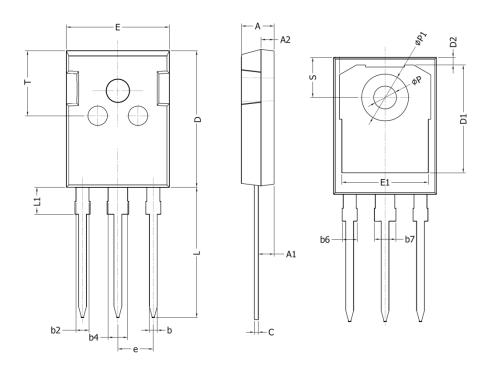


Figure 6 Gate Charge Wave Form





TO-247 Package Information



Comb al	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.90	5.10	0.193	0.201	
A1	2.31	2.51	0.091	0.099	
A2	1.9	2.1	0.075	0.083	
b	1.16	1.26	0.046	0.050	
b2	1.96	2.06	0.077	0.081	
b4	2.96	3.06	0.117	0.120	
b6	-	2.25	-	0.089	
b7	-	3.25	-	0.128	
С	0.59	0.66	0.023	0.026	
D	20.90	21.10	0.823	0.831	
D1	16.25	16.85	0.640	0.663	
D2	1.05	1.35	0.041	0.053	
E	15.70	15.90	0.618	0.626	
E1	13.10	13.50	0.516	0.531	
е	5.436	BSC	0.214 BS	С	
L	19.80	20.10	0.780	0.791	
L1	-	4.30	-	0.169	
Р	3.40	3.60	0.134	0.142	
P1	7.00	7.40	0.276	0.291	
S	6.05	6.25	0.238	0.246	
Т	9.80	10.20	0.386	0.402	





NCE75TD120BT

Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.

单击下面可查看定价,库存,交付和生命周期等信息

>>NCEPOWER(无锡新洁能)